

Supplementary Information

Easily Deposited ZnO Nanorods on Siloxene Nanosheets: Investigation of Morphological Dielectric, Ferroelectric, and Energy Storage Properties.

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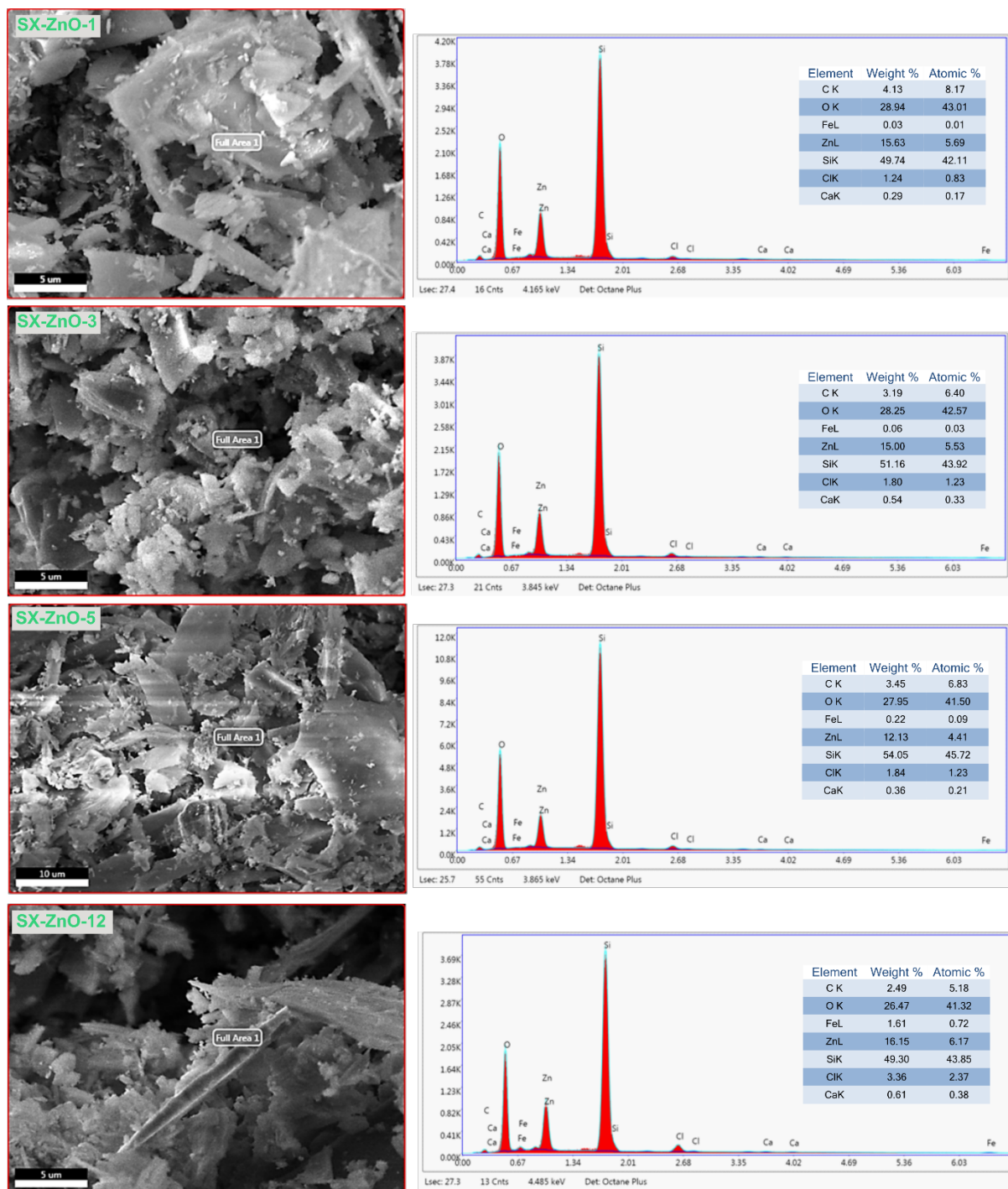


Figure S1: SEM images and EDS results of SX-ZnO nanocomposites.

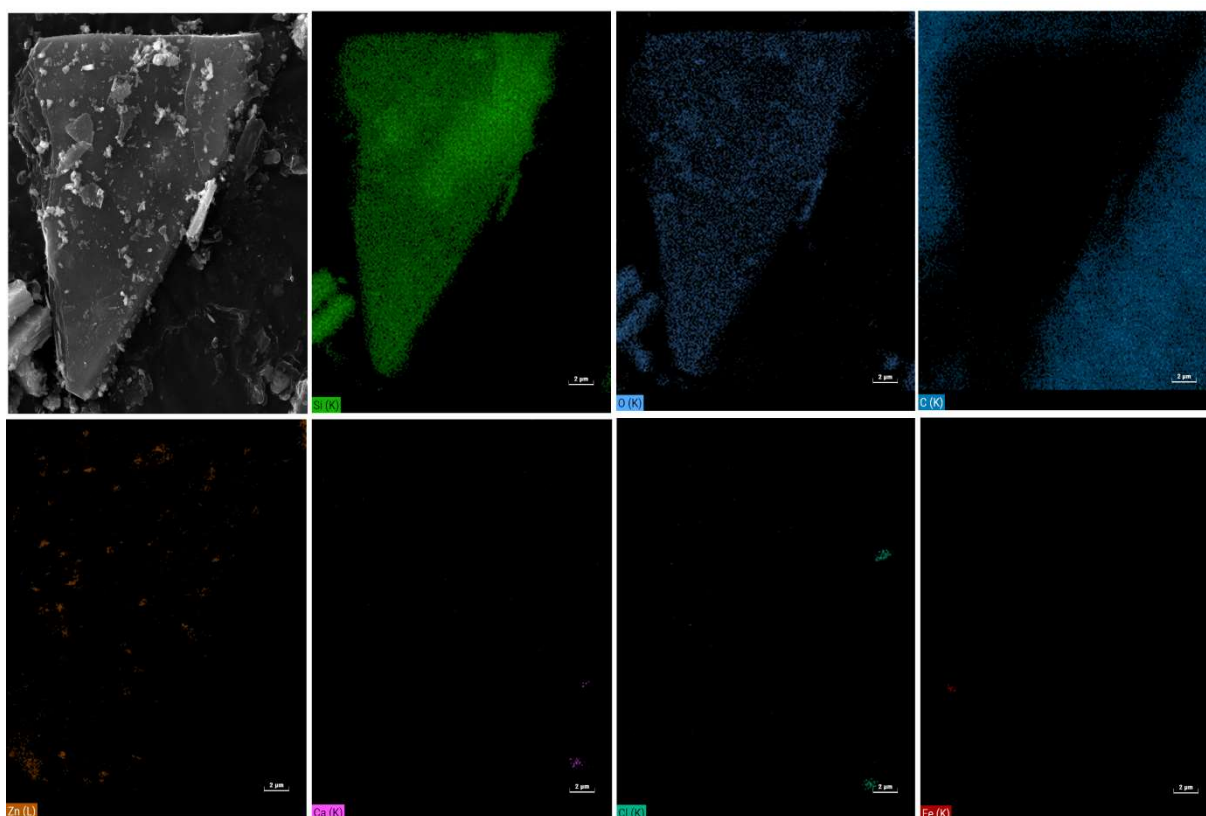


Figure S2: Elemental mapping analysis of SX-ZnO-3.

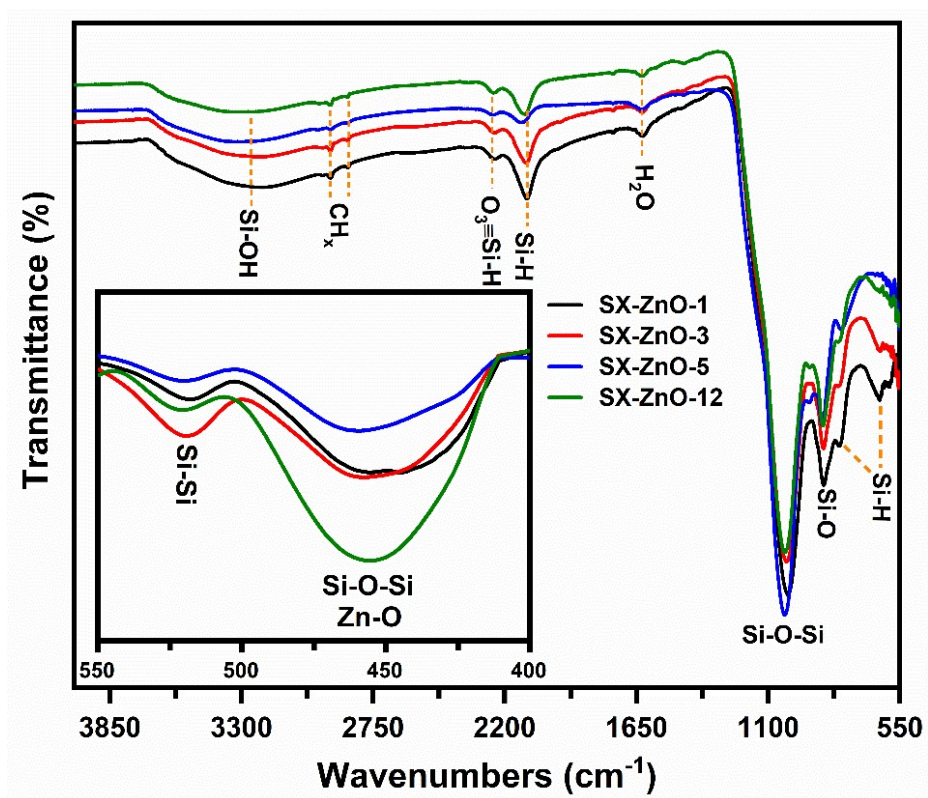


Figure S3: FTIR analysis of the samples.

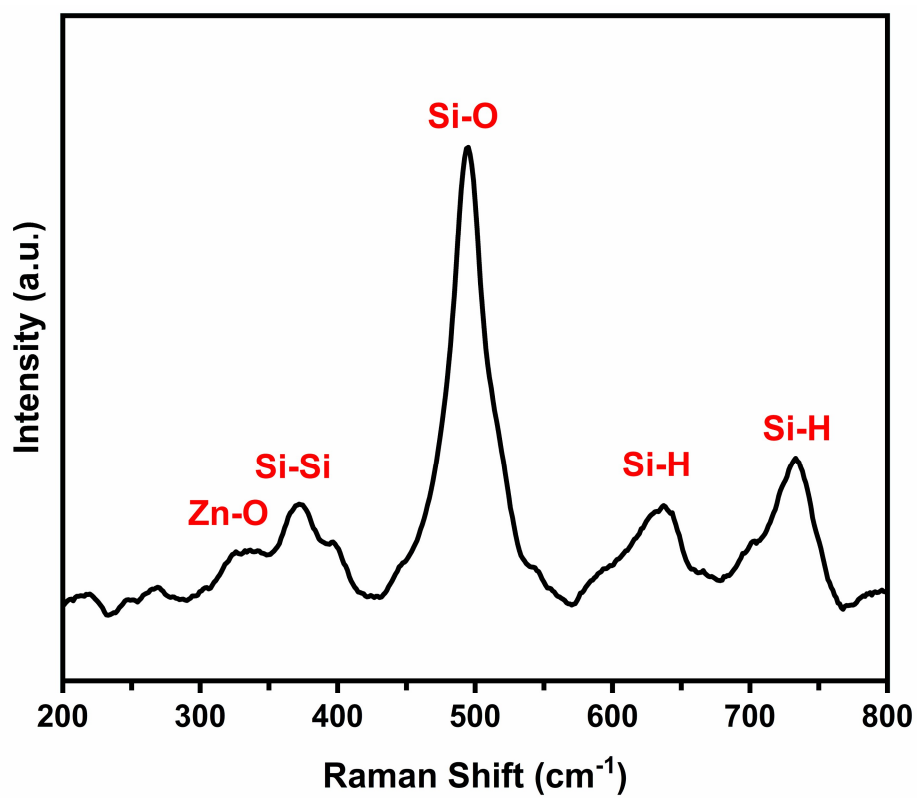


Figure S4: Raman spectrum of SX-ZnO-3.

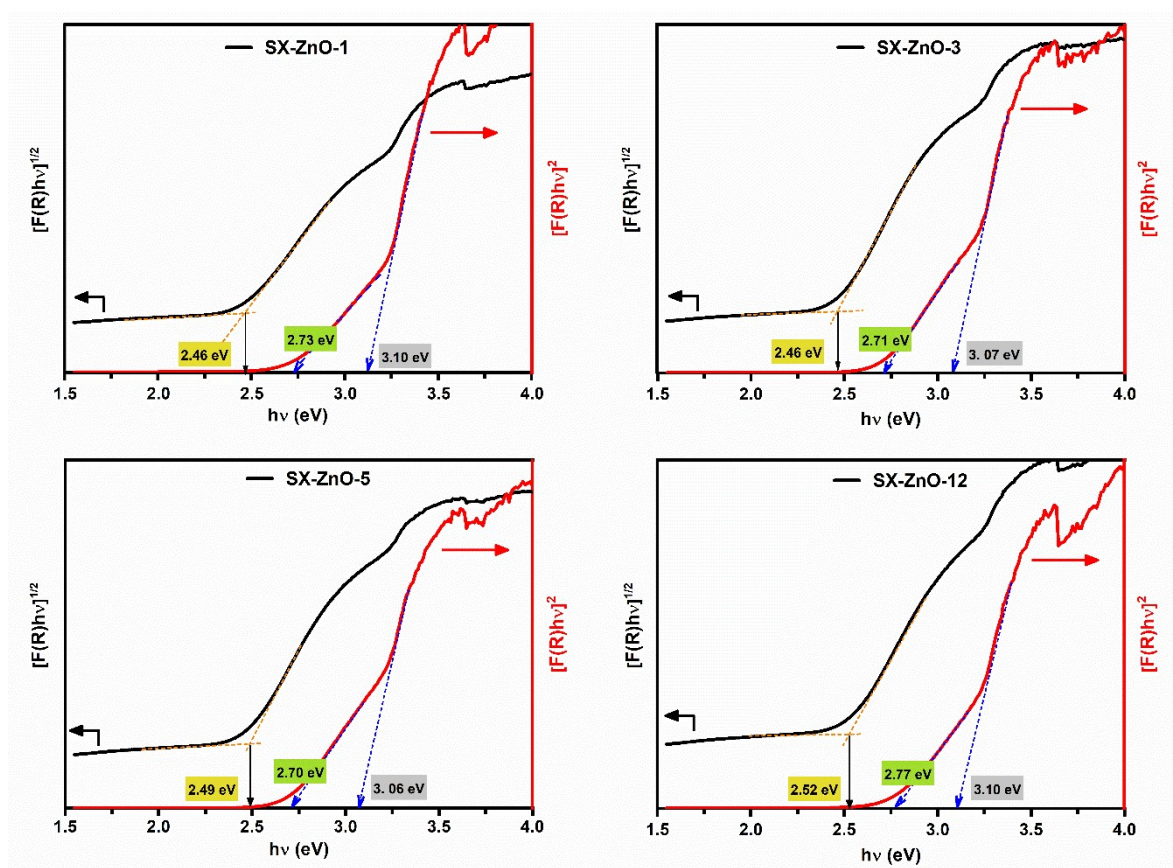


Figure S5: Optical band gaps of SX-ZnO composites.

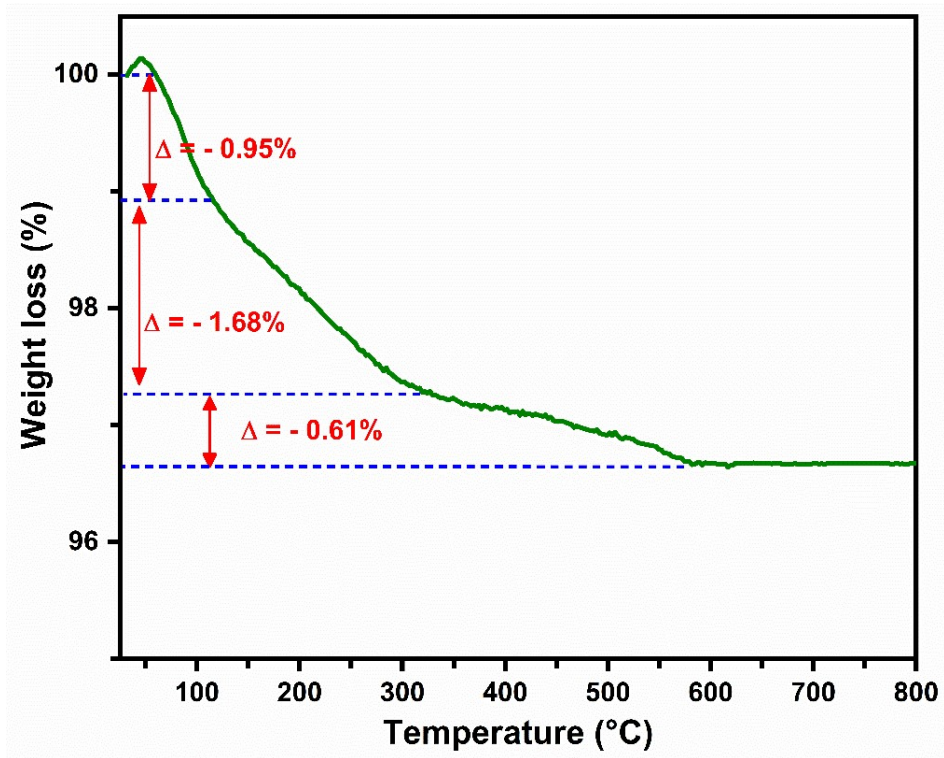


Figure S6: TGA curve of SX-ZnO-3.

S7: Determination of energy density properties

The stored energy density of the pellets are calculated from the following equation:

$$W_s = \int_{P_r}^{P_{max}} E dP \quad (1)$$

where P_{max} is the maximum polarization and P_r is the remnant polarization from the P-E hysteresis loop.

The energy storage efficiency (η) is determined by the relation:

$$\eta = \frac{W_s}{W_{loss} + W_s} \quad (2)$$

where W_{loss} represents the energy loss density which can be calculated from the integrated closed area during discharging process.